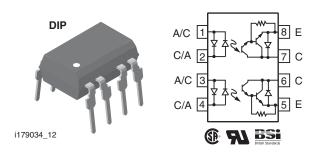
www.vishay.com

Vishay Semiconductors

Optocoupler, Photodarlington Output, AC Input, Internal R_{BE}



DESCRIPTION

The ILD766 are bidirectional input optically coupled isolators. They consist of two gallium arsenide infrared emitting diodes coupled to a silicon NPN photodarlington per channel.

The ILD766 has two isolated channels in a single DIP package.

FEATURES

- Internal R_{BE} for better stability
- BV_{CEO} > 60 V
- AC or polarity insensitive inputs
- Built-in reverse polarity input protection
- Industry standard DIP package
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

APPLICATIONS

• Designed for applications requiring detection or monitoring of AC signals

AGENCY APPROVALS

- UL1577, file no. E52744 system code H or J, double protection
- CSA 93751
- BSI IEC 60950; IEC 60065

ORDERING INFORMATION						
	7 6 6	- #	DIP-8			
PART NUMBER		CTR BIN	7.62 mm			
AGENCY CERTIFIED/PACKAGE	CTR (%)					
Adenci Certified/PACKAGE	2 mA		1 mA			
UL, CSA, BSI	≥ 500		≥ 500			
DIP-8	ILD766-1		ILD766-2			

Note

• Additional options may be possible, please contact sales office.

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	UNIT				
INPUT							
Forward current		١ _F	60	mA			
Power dissipation		P _{diss}	90	mW			
Derate linearly	from 25 °C		1.2	mW/°C			
OUTPUT							
Collector emitter breakdown voltage		BV _{CEO}	60	V			
Collector base breakdown voltage		BV _{CBO}	70	V			
Power dissipation		P _{diss}	100	mW			
Derate linearly	from 25 °C		1.33	mW/°C			

Document Number: 83643



RoHS

COMPLIANT



www.vishay.com

Vishay Semiconductors

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	UNIT				
COUPLER							
Total dissipation		P _{tot}	400	mW			
Derate linearly	from 25 °C		5.3	mW/°C			
Isolation test voltage	t = 1 s	V _{ISO}	5300	V _{RMS}			
Isolation resistance	T _{amb} = 25 °C	R _{IO}	≥ 10 ¹²	Ω			
	T _{amb} = 100 °C	R _{IO}	≥ 10 ¹¹	Ω			
Creepage distance			≥ 7.0	mm			
Clearance distance			≥ 7.0	mm			
Comparative tracking index per DIN IEC 112/VDE 0303, part 1		СТІ	175				
Storage temperature		T _{stg}	- 55 to + 150	°C			
Operating temperature		T _{amb}	- 55 to + 100	°C			
Lead soldering time	at 260 °C		10	S			

Note

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

ELECTRICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT						
Forward voltage	$I_F = \pm 10 \text{ mA}$	V _F		1.2	1.5	V
OUTPUT						
Collector emitter breakdown voltage	I _C = 1.0 mA	BV _{CEO}	60	75		V
Collector base breakdown voltage	I _C = 10 μA	BV _{CBO}	60	90		V
Collector emitter leakage current	V _{CE} = 10 V	I _{CEO}		10	100	nA
COUPLER						
Collector emitter saturation voltage	$I_{F} = \pm 10 \text{ mA}, I_{C} = 10 \text{ mA}$	V _{CEsat}			1.0	V

Note

• Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
DC current transfer ratio	V_{CE} = 5.0 V, I_F = ± 2 mA	CTR _{DC}	500			%

SWITCHING CHARACTERISTICS ($T_{amb} = 25 \text{ °C}$, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Rise time	$\label{eq:V_CC} \begin{split} V_{CC} &= 10 \text{ V}, \text{ I}_{\text{F}} = \pm 2.0 \text{ mA}, \\ R_{\text{L}} &= 100 \ \Omega \end{split}$	t _r		100		110
Fall time		t _f		100		μs



Vishay Semiconductors

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

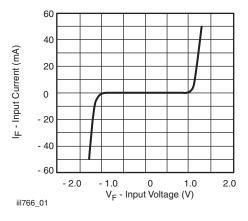


Fig. 1 - Input Characteristics

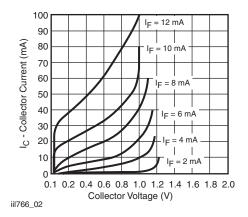


Fig. 2 - Transistor Current vs. Voltage

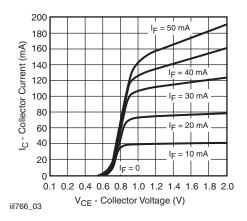


Fig. 3 - Transistor Output Current vs. Voltage

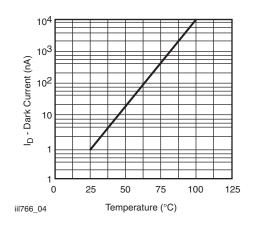


Fig. 4 - I_{CEO} at V_{CE} = 10 V vs. Temperature

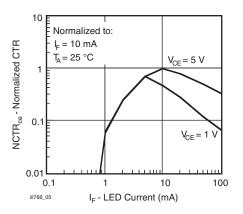


Fig. 5 - Normalized CTR vs. Forward Current

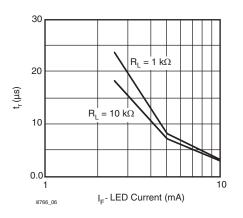
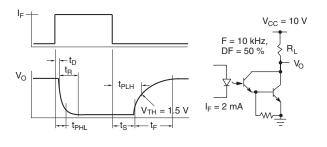


Fig. 6 - t_r vs. Forward Current

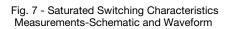
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

Vishay Semiconductors



www.vishay.com

iil766_07



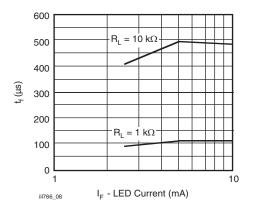


Fig. 8 - t_{fall} vs. Forward Current

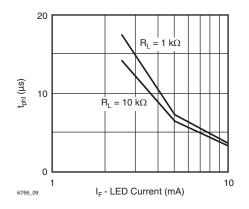


Fig. 9 - t_{phl} vs. Forward Current

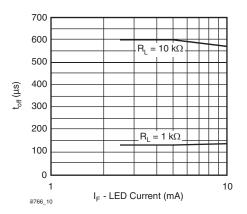


Fig. 10 - toff vs. Forward Current

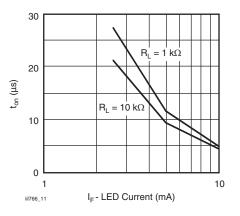


Fig. 11 - t_{on} vs. Forward Current

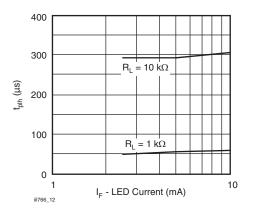


Fig. 12 - t_{plh} vs. Forward Current

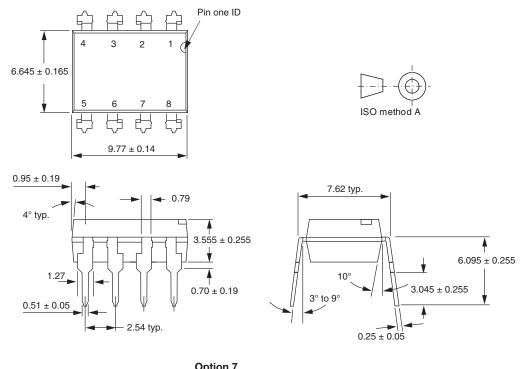
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

Vishay Semiconductors

PACKAGE DIMENSIONS in millimeters

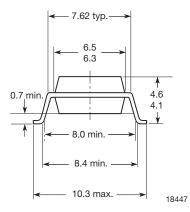
www.vishay.com

VISHA



i178006

Option 7





Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.